

54LVX3245

8-Bit Dual Supply Translating Transceiver with TRI-STATE® Outputs

General Description

The LVX3245 is a dual-supply, 8-bit translating transceiver that is designed to interface between a 3V bus and a 5V bus in a mixed 3V/5V supply environment. The Transmit/Receive (T/R) input determines the direction of data flow. Transmit (active-HIGH) enables data from A ports to B ports; Receive (active-LOW) enables data from B ports to A ports. The Output Enable input, when HIGH, disables both A and B ports by placing them in a TRI-STATE condition. The A port interfaces with the 3V bus; the B port interfaces with the 5V bus.

The LVX3245 is suitable for mixed voltage applications such as systems using 3.3V memories which must interface with existing busses or other components operating at 5.0V.

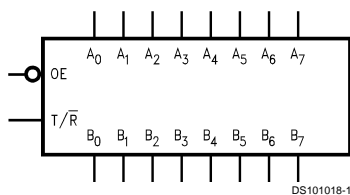
Features

- Bidirectional interface between 3V and 5V buses
- Inputs compatible with TTL level
- 3V data flow at A port and 5V data flow at B port
- Outputs source/sink 24 mA
- Available in ceramic DIP and Flatpack packages
- Implements proprietary EMI reduction circuitry
- Functionally compatible with the 54 series 245
- Standard Microcircuit Drawing (SMD) 5962-9860501

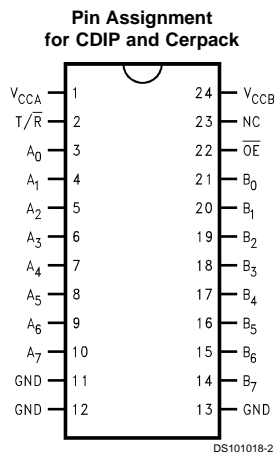
Ordering Code

Order Number	Package Number	Package Description
54LVX3245J-QML	J24F	24-Lead Ceramic Dual-in-line
54LVX3245W-QML	W24C	24-Lead Cerpack

Logic Symbol



Connection Diagram



TRI-STATE® is a registered trademark of National Semiconductor Corporation.

Pin Descriptions

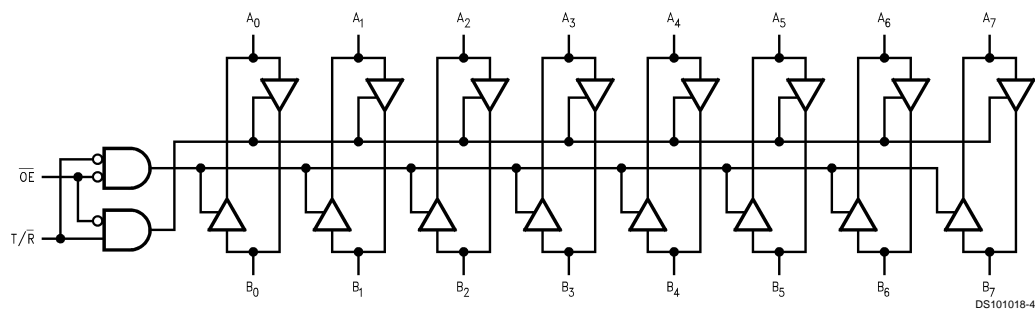
Pin Names	Description
\overline{OE}	Output Enable Input
T/\overline{R}	Transmit/Receive Input
A_0-A_7	Side A Inputs or TRI-STATE Outputs
B_0-B_7	Side B Inputs or TRI-STATE Outputs

Truth Table

Inputs		Outputs
\overline{OE}	T/\overline{R}	
L	L	Bus B Data to Bus A
L	H	Bus A Data to Bus B
H	X	HIGH-Z State

H = High Voltage Level
L = Low Voltage Level
I = Immaterial

Logic Diagram



Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage (V_{CCA} , V_{CCB})	−0.5V to +7.0V
DC Input Voltage (V_I) @ \overline{OE} , T/\overline{R}	−0.5V to $V_{CCB} + 0.5V$
DC Input/Output Voltage ($V_{I/O}$)	
@ A(n)	−0.5V to $V_{CCA} + 0.5V$
@ B(n)	−0.5V to $V_{CCB} + 0.5V$
DC Input Diode Current (I_{IN})	
@ \overline{OE} , T/\overline{R}	±20 mA
DC Output Diode Current (I_{OK})	±50 mA
DC Output Source or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current	
per Output Pin (I_{CC} or I_{GND})	±50 mA
and Max Current @ I_{CCA}	±200 mA
@ I_{CCB}	±200 mA
Storage Temperature Range (T_{STG})	−65°C to +150°C

Recommended Operating Conditions (Note 2)

Supply Voltage	
V_{CCA}	2.7V to 3.6V
V_{CCB}	4.5V to 5.5V
Input Voltage (V_I) @ \overline{OE} , T/\overline{R}	0V to V_{CCB}
Input/Output Voltage ($V_{I/O}$)	
@ A(n)	0V to V_{CCA}
@ B(n)	0V to V_{CCB}
Free Air Operating Temperature (T_A)	−55°C to +125°C
Minimum Input Edge Rate ($\Delta t/\Delta V$)	8 ns/V
V_{IN} from 30% to 70% of V_{CC}	
V_{CC} @ 3.0V, 4.5V, 5.5V	

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: Unused Pins (inputs and I/Os) must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter		V_{CCA} (V)	V_{CCB} (V)	$T_A = -55^\circ\text{C to } +125^\circ\text{C}$	Units	Conditions
					Guaranteed Limits		
V_{IHA}	Minimum High Level Input Voltage	A(n), T/\overline{R} , \overline{OE}	3.6	5.0	2.0	V	$V_{OUT} \leq 0.1V$ or $\geq V_{CC} - 0.1V$
			2.7	5.0	2.0		
V_{IHB}		B(n)	3.3	4.5	2.0		
			3.3	5.5	2.0		
V_{ILA}	Maximum Low Level Input Voltage	A(n), T/\overline{R} , \overline{OE}	3.6	5.0	0.8	V	$V_{OUT} \leq 0.1V$ or $\geq V_{CC} - 0.1V$
			2.7	5.0	0.8		
V_{ILB}		B(n)	3.3	4.5	0.8		
			3.3	5.5	0.8		
V_{OHA}	Minimum High Level Output Voltage		2.7	4.5	2.6	V	$I_{OH} = -100 \mu A$ $I_{OH} = -100 \mu A$ $I_{OH} = -12 \text{ mA}$ $I_{OH} = -12 \text{ mA}$ $I_{OH} = -24 \text{ mA}$
			3.6	5.5	3.5		
			2.7	4.5	2.2		
			3.0	4.5	2.4		
			3.0	4.5	2.2		
V_{OHB}			2.7	4.5	4.4	V	$I_{OH} = -100 \mu A$ $I_{OH} = -100 \mu A$ $I_{OH} = -24 \text{ mA}$
			3.6	5.5	5.4		
			3.0	4.5	3.7		
V_{OLA}	Maximum Low Level Output Voltage		2.7	4.5	0.1	V	$I_{OL} = 100 \mu A$ $I_{OL} = 100 \mu A$ $I_{OL} = 12 \text{ mA}$ $I_{OL} = 12 \text{ mA}$ $I_{OL} = 24 \text{ mA}$
			3.6	5.5	0.1		
			2.7	4.5	0.4		
			3.0	4.5	0.3		
			3.0	4.5	0.4		
V_{OLB}			2.7	4.5	0.1	V	$I_{OL} = 100 \mu A$ $I_{OL} = 100 \mu A$ $I_{OL} = 24 \text{ mA}$
			3.6	5.5	0.1		
			3.0	4.5	0.4		

DC Electrical Characteristics (Continued)

Symbol	Parameter		V _{CCA} (V)	V _{CCB} (V)	T _A = -55°C to +125°C	Units	Conditions
					Guaranteed Limits		
I _{IN}	Maximum Input Leakage Current @ \overline{OE} , T/\overline{R}		3.6	5.5	±1.0	μA	V _I = V _{CCB} , GND
I _{OZA}	Maximum TRI-STATE Output Leakage @ A(n)		3.6	5.5	±5.0	μA	T/\overline{R} = 0.0V, \overline{OE} = V _{IH} , V _O = V _{CCA} , GND
I _{OZB}	Maximum TRI-STATE Output Leakage @ B(n)		3.6	5.5	±5.0	μA	T/\overline{R} = 3.6V, \overline{OE} = V _{IH} , V _O = V _{CCB} , GND
ΔI _{CC}	Maximum	B(n)	3.6	5.5	1.5	mA	V _I = V _{CCB} - 2.1V, T/\overline{R} = 0.0V
	I _{CCT} /Input @	A(n), T/\overline{R} , \overline{OE}	3.6	5.5	500	μA	V _I = V _{CCA} - 0.6V T/\overline{R} = 3.6V
I _{CCA}	Quiescent V _{CCA} Supply Current		3.6	5.5	10	μA	B(n) = V _{CCB} or GND \overline{OE} = GND, T/\overline{R} = GND
I _{CCB}	Quiescent V _{CCB} Supply Current		3.6	5.5	40	μA	A(n) = V _{CCA} or GND \overline{OE} = GND, T/\overline{R} = V _{CCA}
V _{OLPA}	Quiet Output Maximum		3.3	5.0	1.1	V	(Note 4) (Note 5)
V _{OLPB}	Dynamic V _{OL}		3.3	5.0	1.6		
V _{OLVA}	Quiet Output Minimum		3.3	5.0	-0.8	V	(Note 4) (Note 5)
V _{OLVB}	Dynamic V _{OL}		3.3	5.0	-1.1		

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: Worst case package.

Note 5: Max number of outputs defined as (n). Data inputs are driven 0V to V_{CC} level; one output at GND.

AC Electrical Characteristics

Symbol	Parameters	T _A = -55°C to +125°C C _L = 50 pF V _{CCA} = 3.3V (Note 7) V _{CCB} = 5.0V (Note 6)		T _A = -55°C to +125°C C _L = 50 pF V _{CCA} = 2.7V V _{CCB} = 5.0V (Note 6)		Units
		Min	Max	Min	Max	
t _{PHL}	Propagation Delay A to B	1.0	8.5	1.0	9.0	ns
t _{PLH}	Propagation Delay B to A	1.0	8.0	1.0	8.5	ns
t _{PZL}	Output Enable Time \overline{OE} to B	1.0	8.5	1.0	9.0	ns
t _{PZH}	Output Enable Time \overline{OE} to A	1.0	9.5	1.0	10.5	ns
t _{PHZ}	Output Disable Time \overline{OE} to B	1.0	7.5	1.0	7.5	ns
t _{PLZ}	Output Disable Time \overline{OE} to A	1.0	7.0	1.0	7.0	ns
t _{OSHL} t _{OSLH}	Output to Output Skew (Note 8) Data to Output		1.5		1.5	ns

Note 6: Voltage Range 5.0V is 5.0V ±0.5V.

Note 7: Voltage Range 3.3V is 3.3V ±0.3V.

Note 8: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH to LOW (t_{OSHL}) or LOW to HIGH (t_{OSLH}). Parameter guaranteed by design.

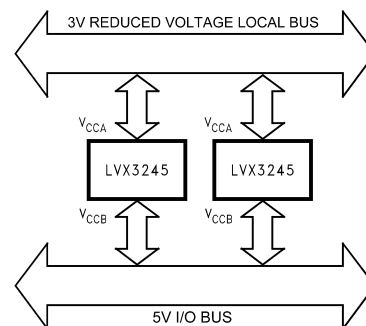
Capacitance

Symbol	Parameter	Max	Units	Conditions
C _{IN}	Input Capacitance	10	pF	V _{CC} = Open
C _{I/O}	Input/Output Capacitance	12	pF	V _{CCA} = 3.3V V _{CCB} = 5.0V
C _{PD}	Power Dissipation Capacitance	50	pF	V _{CCB} = 5.0V V _{CCA} = 3.3V

Note 9: C_{PD} is measured at 10 MHz

8-Bit Dual Supply Translating Transceiver

The LVX3245 is a dual supply device capable of bidirectional signal translation. This level shifting ability provides an efficient interface between low voltage CPU local bus with memory and a standard bus defined by 5V I/O levels. The device control inputs can be controlled by either the low voltage CPU and core logic or a bus arbitrator with 5V I/O levels. Manufactured on a sub-micron CMOS process, the LVX3245 is suitable for mixed voltage applications such as systems using 3.3V memories which must interface with existing buses or other components operating at 5.0V.



DS101018-3

Applications: Mixed Mode Dual Supply Interface Solution

LVX3245 is designed to solve 3V/5V interfacing issues when CMOS devices cannot tolerate I/O levels above their applied V_{CC} . If an I/O pin of 3V ICs is driven by 5V ICs, the P-Channel transistor in 3V ICs will conduct causing current flow from I/O bus to the 3V power supply. The resulting high current flow can cause destruction of 3V ICs through latchup effects. To prevent this problem, a current limiting resistor is used typically under direct connection of 3V ICs and 5V ICs, but it causes speed degradation.

In a better solution, the LVX3245 configures two different output levels to handle the dual supply interface issues. The "A" port is a dedicated 3V port to interface 3V ICs. The "B" port is a dedicated port to interface 5V ICs. *Figure 1* shows how LVX3245 fits into a system with 3V subsystem and 5V subsystem.

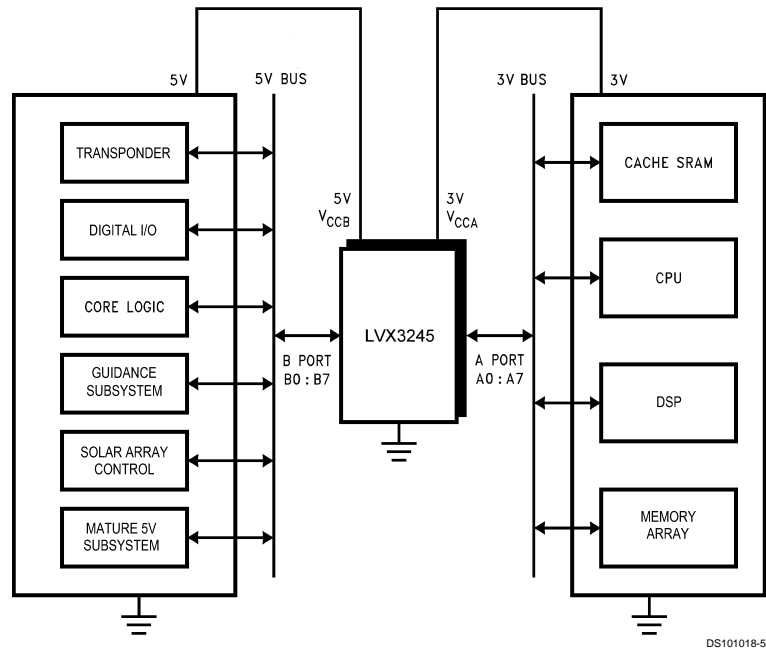
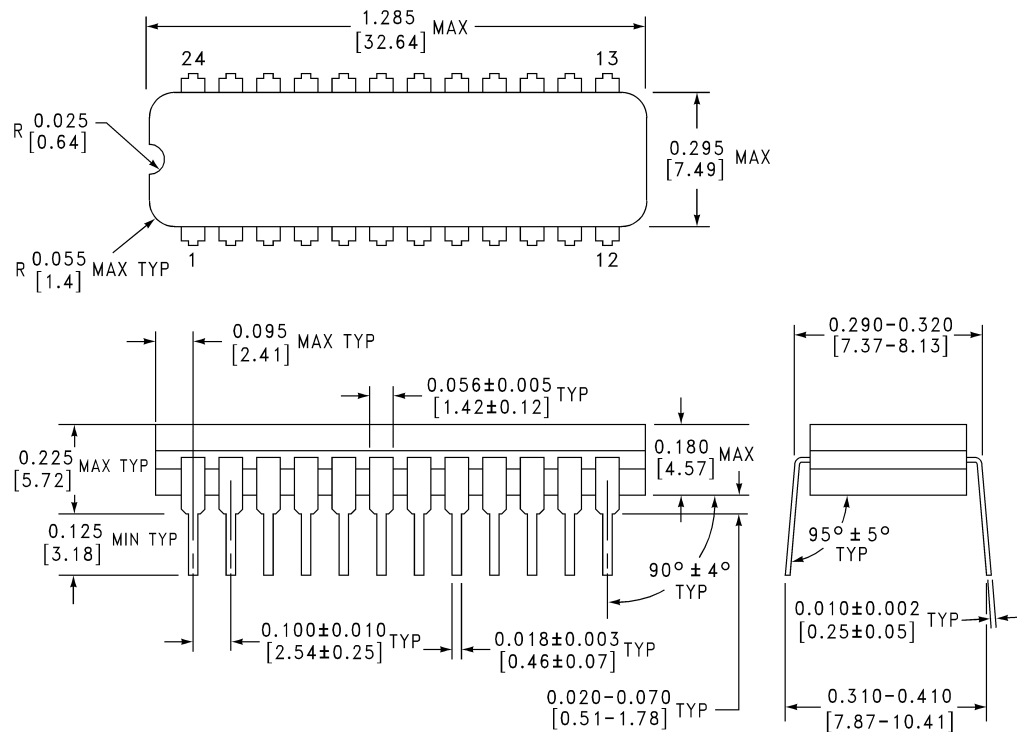


FIGURE 1. LVX3245 Fits into a System with 3V Subsystem and 5V Subsystem

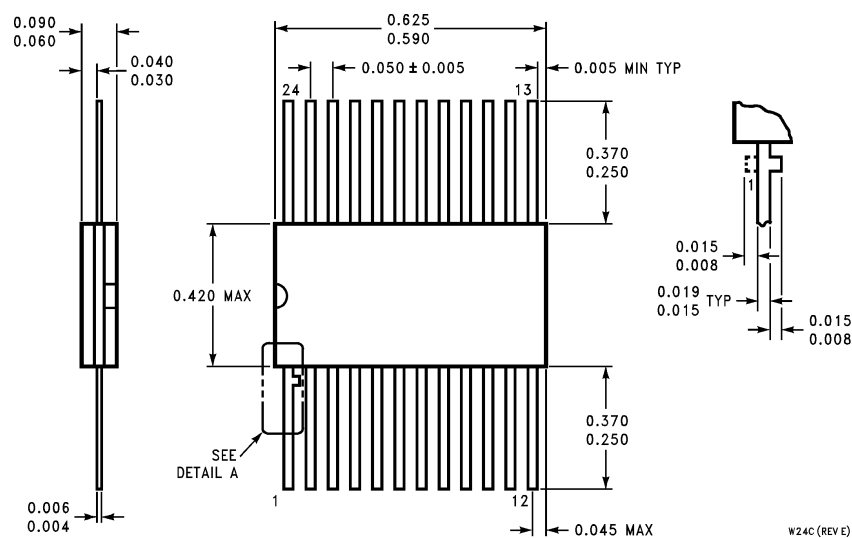
DS101018-5

Physical Dimensions inches (millimeters) unless otherwise noted



J24F (REV. H)

**24-Lead Ceramic DIP
Package Number J24F**



W24C (REV E)

**24-Lead Cerpack
Package Number W24C**

Notes

LIFE SUPPORT POLICY

NATIONAL'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT OF NATIONAL SEMICONDUCTOR CORPORATION. As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.



National Semiconductor Corporation
Americas
Tel: 1-800-272-9959
Fax: 1-800-737-7018
Email: support@nsc.com

www.national.com

National Semiconductor Europe

Fax: +49 (0) 1 80-530 85 86
Email: europe.support@nsc.com
Deutsch Tel: +49 (0) 1 80-530 85 85
English Tel: +49 (0) 1 80-532 78 32
Français Tel: +49 (0) 1 80-532 93 58
Italiano Tel: +49 (0) 1 80-534 16 80

National Semiconductor Asia Pacific Customer Response Group

Tel: 65-2544466
Fax: 65-2504466
Email: sea.support@nsc.com

National Semiconductor Japan Ltd.

Tel: 81-3-5639-7560
Fax: 81-3-5639-7507